

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Takatoshi Tsujimura et al.

Group Art Unit:

1762

Serial No.:

10/693,244

Examiner:

David P. Turocy

Filed:

October 24, 2003

For:

Forming a Thin Film Structure

Atty. Dkt. No.:

CMO.0012US

(P030096ATZLUS)

## Mail Stop Amendment

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## <u>INFORMATION</u> DISCLOSURE STATEMENT

Dear Sir:

Applicant submits the references listed on the attached form PTO 1449 together with any required copies of such references.

Please apply any additional charges or credits to Deposit Account No. 20-1504 (CMO.0012US).

Respectfully submitted,

Date: Sept 7, 2007

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I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated above and is addressed to the Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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